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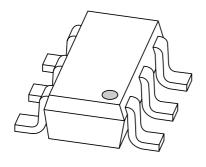
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# PIMT1 PNP general purpose double transistor

Product data sheet 2001 Oct 22



# PNP general purpose double transistor

PIMT1

#### **FEATURES**

- 600 mW total power dissipation
- Low current (max. 100 mA)
- Low voltage (max. 40 V)
- Reduces number of components and required PCB area
- · Reduced pick and place costs.

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

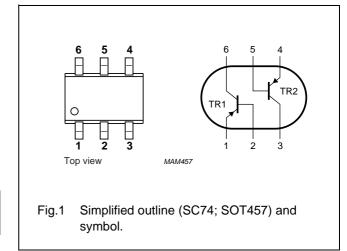
PNP transistor pair in an SC-74 (SOT457) plastic package.

#### **MARKING**

TYPE NUMBER	MARKING CODE		
PIMT1	M1		

#### **PINNING**

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transis	Per transistor					
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-50	V	
$V_{CEO}$	collector-emitter voltage	open base	_	-40	V	
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V	
I <sub>C</sub>	collector current (DC)		_	-100	mA	
I <sub>CM</sub>	peak collector current		_	-200	mA	
I <sub>BM</sub>	peak base current		-	-200	mA	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	-	300	mW	
T <sub>stg</sub>	storage temperature		-65	+150	°C	
Tj	junction temperature		_	150	°C	
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C	
Per device	Per device					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	600	mW	

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and mounting pad for collector 1 cm<sup>2</sup>.

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# PNP general purpose double transistor

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	208	K/W

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and mounting pad for collector 1 cm<sup>2</sup>.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transis	Per transistor					
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0$	_	-100	nA	
		$V_{CB} = -30 \text{ V}; I_E = 0; T_j = 150 ^{\circ}\text{C}$	_	-10	μΑ	
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -4 \text{ V}; I_C = 0$	_	-100	nA	
h <sub>FE</sub>	DC current gain	$V_{CE} = -6 \text{ V}; I_{C} = -1 \text{ mA}$	120	_		
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -50 \text{ mA}$ ; $I_B = -5 \text{ mA}$ ; note 1	_	-200	mV	
C <sub>c</sub>	collector capacitance	$V_{CB} = -12 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	_	2.2	pF	
f <sub>T</sub>	transition frequency	$V_{CE} = -12 \text{ V}; I_{C} = -2 \text{ mA};$ f = 100 MHz	100	-	MHz	

#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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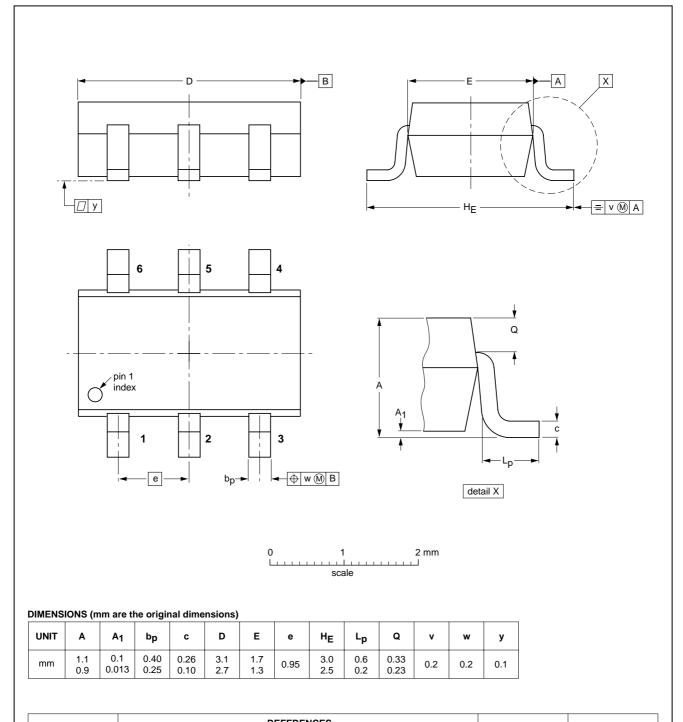
# PNP general purpose double transistor

PIMT1

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 6 leads

**SOT457** 



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT457			SC-74			<del>97-02-28</del> 01-05-04

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#### PNP general purpose double transistor

PIMT1

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
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### **NXP Semiconductors**

#### **Customer notification**

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#### **Contact information**

For additional information please visit: http://www.nxp.com

For sales offices addresses send e-mail to: salesaddresses@nxp.com

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